

J Murray Gibson

List of Publications by Year in descending order

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19
papers

378
citations

1306789

7
h-index

996533

15
g-index

19
all docs

19
docs citations

19
times ranked

267
citing authors

#	ARTICLE	IF	CITATIONS
1	Dynamic observations of interface propagation during silicon oxidation. Physical Review Letters, 1992, 68, 1782-1785.	2.9	124
2	Strain Evolution in Coherent Ge/Si Islands. Physical Review Letters, 2000, 84, 1958-1961.	2.9	77
3	Elastic-displacement field of an isolated surface step. Physical Review B, 1994, 49, 13848-13858.	1.1	40
4	Direct measurement of strain in a Ge island on Si(001). Applied Physics Letters, 1999, 75, 46-48.	1.5	40
5	Dome-to-pyramid shape transition in Ge/Si islands due to strain relaxation by interdiffusion. Applied Physics Letters, 2000, 77, 1623-1625.	1.5	39
6	Evolution of coherent islands during strained-layer Volmer-Weber growth of Si on Ge(111). Physical Review B, 2001, 63, .	1.1	20
7	TEM measurement of strain in coherent quantum heterostructures. Ultramicroscopy, 2000, 84, 225-233.	0.8	16
8	Visualization of Dynamic Near-Surface Processes. MRS Bulletin, 1994, 19, 38-43.	1.7	7
9	Strain in Coherent Ge Quantum Islands on Si Measured by Transmission Electron Microscopy. Materials Research Society Symposia Proceedings, 1999, 571, 49.	0.1	4
10	Control of Medium Range Order in Amorphous Silicon via Ion and Neutral Bombardment. Materials Research Society Symposia Proceedings, 2001, 664, 2731.	0.1	3
11	Silicon Surface Morphology and the Reaction of Silicon with Oxygen. Materials Research Society Symposia Proceedings, 1992, 259, 87.	0.1	2
12	Fluctuation Microscopy Studies of Medium-range Order Structures in Amorphous Tetrahedral Semiconductors. Materials Research Society Symposia Proceedings, 2000, 638, 1.	0.1	2
13	Medium-Range Order Structures of Amorphous Diamond-Like Carbon Films. Materials Research Society Symposia Proceedings, 2001, 675, 1.	0.1	2
14	A Damage Model for Disordered Structures in Ion Irradiated Silicon. Materials Research Society Symposia Proceedings, 2000, 647, 1.	0.1	1
15	A Damage Model for Disordered Structures in Ion Irradiated Silicon. Materials Research Society Symposia Proceedings, 2000, 650, 1411.	0.1	1
16	The effect of processing conditions on the structure of buried interfaces between silicon and silicon dioxide. Materials Research Society Symposia Proceedings, 1996, 448, 303.	0.1	0
17	Identification of Shape Transitions in Coherent Ge/Si Islands Using Transmission Electron Microscopy. Materials Research Society Symposia Proceedings, 1999, 583, 137.	0.1	0
18	Shape Reversal of Ge/Si Domes to Pyramids Via Si-Ge Intermixing and Strain Reduction. Materials Research Society Symposia Proceedings, 1999, 583, 45.	0.1	0

#	ARTICLE	IF	CITATIONS
19	In-Situ Transmission Electron Microscopy of Thin Film Growth. , 1997, , 149-171.		0